

Abstract Submitted  
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**Strain-induced** **Ferroelectricity**  
**in Ruddlesden-Popper  $\text{Sr}(n+1)\text{Ti}(n)\text{O}(3n+1)$  Phases** N. ORLOFF, NIST,  
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University, I. TAKEUCHI, University of Maryland, J. C. BOOTH, NIST, D. G.  
SCHLOM, Cornell University — We performed broadband in-plane dielectric mea-  
surements of thin-film  $\text{Sr}(n+1)\text{Ti}(n)\text{O}(3n+1)$  ( $n = 2, 3, 4, 5, 6$ ) Ruddlesden-Popper  
homologous series as a function of temperature and bias field. The effect of strain on  
these materials is interesting, because  $\text{SrTiO}_3$ , the  $n = \infty$  series member, exhibits  
ferroelectricity at room temperature when strained on  $\text{DyScO}_3$  substrates. Here, we  
explore the effect of strain on the dielectric properties of  $\text{Sr}(n+1)\text{Ti}(n)\text{O}(3n+1)$  ( $n$   
 $= 2, 3, 4, 5, 6$ ) thin-films on LSAT,  $\text{DyScO}_3$  and  $\text{GdScO}_3$ .

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